

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low V_F
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction





| Part Number | Package | Marking |
|-------------|-----------|---------|
| HC4D12120A | TO-220-2L | H4121TJ |



TO-220-2L





Maximum Ratings ($T_c = 25 \, ^{\circ}\text{C}$ unless otherwise specified)

| Symbol | Parameter | Value | Unit | Test Conditions |
|---------------------|--|----------------|------------------|--|
| V_{RRM} | Repetitive Peak Reverse Voltage | 1200 | ٧ | |
| V _{RSM} | Surge Peak Reverse Voltage | 1200 | V | |
| V _R | DC Blocking Voltage | 1200 | V | |
| I _F | Continuous Forward Current | 39 20 12 | А | T _c =25°C T _c =135°C T _c =153°C |
| I _{FRM} | Repetitive Peak Forward Surge Current | 84 63 | Α | T _c =25°C, t _p = 10 ms, Half Sine Wave T _c =110°C, t _p =10 ms, Half Sine Wave |
| I _{FSM} | Non-Repetitive Peak Forward Surge Current | 130 108 | Α | T_c =25°C, t_p = 10 ms, Half Sine Wave T_c =110°C, t_p = 10 ms, Half Sine Wave |
| ∫i²dt | i ² dt value | 84.5 58 | A ² s | T_C = 25°C, t_p =10ms,Half Sine Pulse T_C = 110°C, t_p =10ms,Half Sine Pulse |
| P _{tot} | Power Dissipation | 150 65 | W | T _c =25°C T _c =110°C |
| T_{J} , T_{stg} | Operating Junction and Storage Temperature | -55 to +150 | °C | |
| T _J | Operating junction Range | -55 to +175 | °C | |

Electrical Characteristics

| Parameter | Symbol | Value | | | Unit | Test Condition | |
|-------------------------|----------------|-------|------|------|-------|--|--|
| rarameter | Syllibol | min. | typ. | max. | Offic | rest Condition | |
| | V _F | | | | | I _F =12A | |
| Forward Voltage | | - | 1.35 | 1.7 | V | T _j =25°C | |
| | | - | 2.0 | | | T _j =175°C | |
| | | | | | | V _R =1200V | |
| Reverse Current | I _R | - | - | 150 | μΑ | T _j =25°C | |
| | | - | - | 300 | | T _j =175°C | |
| | | | | | nC | V _R =800V,T _j =25℃ | |
| Total Capacitive Charge | Q_{C} | ı | 75.6 | ı | | $V_R = 800V, T_j = 25^{\circ}C$ $Q_C = \int_0^{V_R} C(V) dV$ | |
| | С | | | | pF | T _j =25℃, f=1MHz | |
| Total Capacitance | | - | 1022 | - | | V _R =0V | |
| | | - | 71 | - | | V _R =400V | |
| | | - | 55 | - | | V _R =800V | |

Thermal Characteristics

| Symbol | Parameter | Тур. | Unit |
|------------------|--|------|------|
| R _{eJC} | Thermal Resistance from Junction to Case | 1.0 | °C/W |

Characteristics Curve

Fig 1: Forward Characteristics

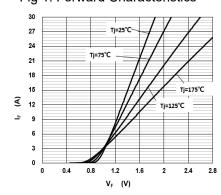
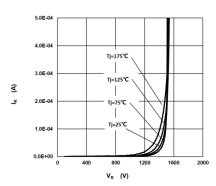


Fig 2: Reverse Characteristics



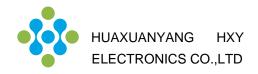


Fig 3: Current Derating

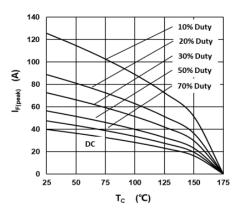


Fig 5: Capacitance vs. Reverse Voltage

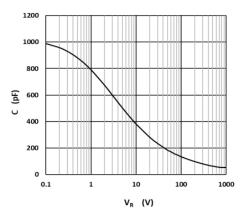


Fig 7: Typical Capacitance Stored Energy

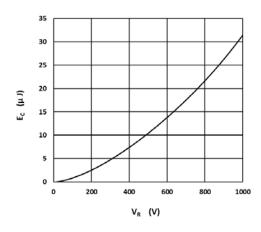


Fig 4: Power Derating

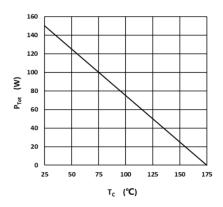


Fig 6: Reverse Charge vs. Reverse Voltage

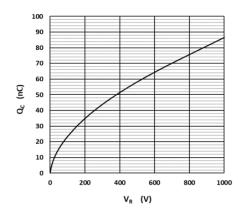
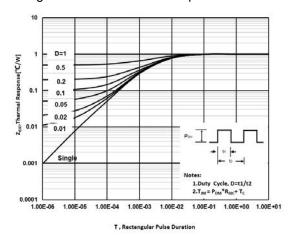
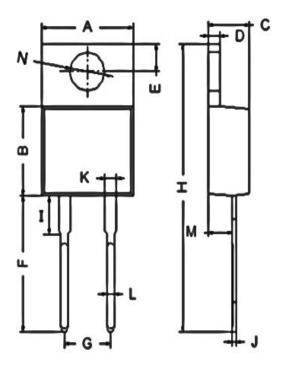


Fig 8: Transient Thermal Impandance





Package Information TO-220-2L



| POS | Millimeters | | |
|-----|-------------|-------|--|
| | Min. | Max. | |
| Α | 9.80 | 10.50 | |
| В | 8.60 | 9.20 | |
| С | 4.37 | 4.77 | |
| D | 1.07 | 1.47 | |
| E | 2.40 | 3.00 | |
| F | 13.14 | 14.20 | |
| G | 4.90 | 5.24 | |
| Н | 28.00 | 29.20 | |
| I | 3.50 | 4.00 | |
| J | 0.28 | 0.50 | |
| K | 1.20 | 1.50 | |
| L | 0.70 | 0.90 | |
| М | 2.40 | 2.90 | |
| N | 3.70 | 4.00 | |

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